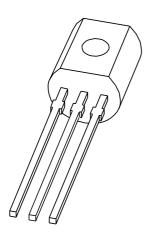
DISCRETE SEMICONDUCTORS

DATA SHEET



BF421; BF423PNP high voltage transistors

Product specification Supersedes data of 1996 Dec 09 2004 Nov 10





Philips Semiconductors Product specification

PNP high voltage transistors

BF421; BF423

FEATURES

• Low feedback capacitance.

APPLICATIONS

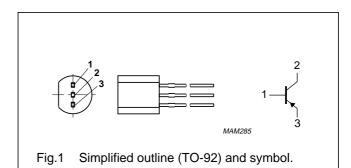
• Class-B video output stages in colour television and professional monitor equipment.

DESCRIPTION

PNP transistors in a TO-92 plastic package. NPN complements: BF420 and BF422.

PINNING

| PIN | DESCRIPTION |
|-----|-------------|
| 1 | base |
| 2 | collector |
| 3 | emitter |



ORDERING INFORMATION

| TYPE NUMBER | | PACKAGE | |
|-------------|--------|---|---------|
| TIPE NUMBER | NAME | DESCRIPTION | VERSION |
| BF421 | SC-43A | plastic single-ended leaded (through hole) package; 3 leads | SOT54 |
| BF423 | | | |

QUICK REFERENCE DATA

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|------------------|---------------------------|---|------|------|------|
| V _{CBO} | collector-base voltage | open emitter | | | |
| | BF421 | | _ | -300 | V |
| | BF423 | | _ | -250 | V |
| V _{CEO} | collector-emitter voltage | open base | | | |
| | BF421 | | _ | -300 | V |
| | BF423 | | _ | -250 | V |
| I _{CM} | peak collector current | | - | -100 | mA |
| P _{tot} | total power dissipation | T _{amb} ≤ 25 °C | _ | 830 | mW |
| h _{FE} | DC current gain | $V_{CE} = -20 \text{ V}; I_{C} = -25 \text{ mA}$ | 50 | _ | |
| C _{re} | feedback capacitance | $V_{CE} = -30 \text{ V}; I_C = I_c = 0 \text{ A}; f = 1 \text{ MHz}$ | _ | 1.6 | pF |
| f _T | transition frequency | $V_{CE} = -10 \text{ V}; I_{C} = -10 \text{ mA}; f = 100 \text{ MHz}$ | 60 | _ | MHz |

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Philips Semiconductors Product specification

PNP high voltage transistors

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LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|------------------|---------------------------|----------------------------------|------|------|------|
| V _{CBO} | collector-base voltage | open emitter | | | |
| | BF421 | | _ | -300 | V |
| | BF423 | | _ | -250 | V |
| V _{CEO} | collector-emitter voltage | open base | | | |
| | BF421 | | _ | -300 | V |
| | BF423 | | _ | -250 | V |
| V _{EBO} | emitter-base voltage | open collector | - | -5 | V |
| I _C | collector current (DC) | | _ | -50 | mA |
| I _{CM} | peak collector current | | _ | -100 | mA |
| I _{BM} | peak base current | | _ | -50 | mA |
| P _{tot} | total power dissipation | T _{amb} ≤ 25 °C; note 1 | _ | 830 | mW |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| Tj | junction temperature | | _ | 150 | °C |
| T _{amb} | ambient temperature | | -65 | +150 | °C |

Note

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | CONDITIONS | VALUE | UNIT |
|----------------------|---|------------|-------|------|
| R _{th(j-a)} | thermal resistance from junction to ambient | note 1 | 150 | K/W |

Note

CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|--------------------|--------------------------------------|--|------|------|------|
| I _{CBO} | collector-base cut-off current | V _{CB} = -200 V; I _E = 0 A | _ | -10 | nA |
| | | $V_{CB} = -200 \text{ V}; I_E = 0 \text{ A}; T_j = 150 ^{\circ}\text{C}$ | _ | -10 | μΑ |
| I _{EBO} | emitter-base cut-off current | $V_{EB} = -5 \text{ V}; I_C = 0 \text{ A}$ | _ | -50 | nA |
| h _{FE} | DC current gain | $V_{CE} = -20 \text{ V}; I_{C} = -25 \text{ mA}$ | 50 | _ | |
| V _{CEsat} | collector-emitter saturation voltage | $I_C = -30 \text{ mA}; I_B = -5 \text{ mA}$ | _ | -0.6 | V |
| C _{re} | feedback capacitance | $V_{CE} = -30 \text{ V}; I_C = i_c = 0 \text{ A}; f = 1 \text{ MHz}$ | _ | 1.6 | pF |
| f _T | transition frequency | $V_{CE} = -10 \text{ V}; I_{C} = -10 \text{ mA}; f = 100 \text{ MHz}$ | 60 | _ | MHz |

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^{1.} Transistor mounted on a printed-circuit board.

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Philips Semiconductors Product specification

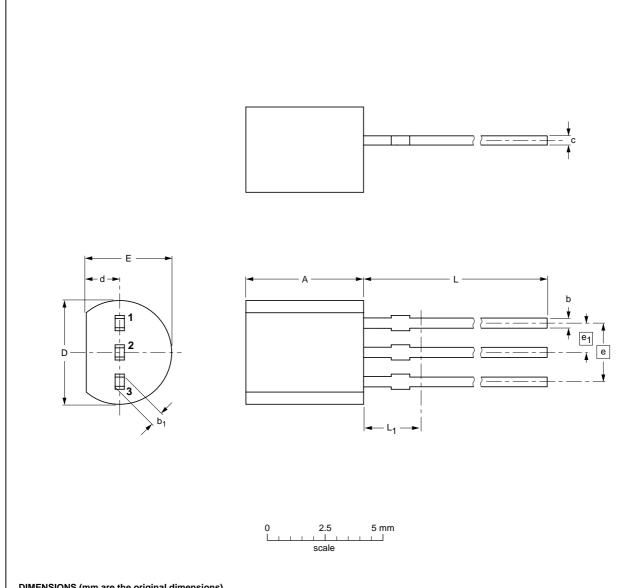
PNP high voltage transistors

BF421; BF423

PACKAGE OUTLINE

Plastic single-ended leaded (through hole) package; 3 leads

SOT54



DIMENSIONS (mm are the original dimensions)

| UNIT | A | b | b ₁ | С | D | d | E | е | e ₁ | L | L ₁ ⁽¹⁾ max. | |
|------|------------|--------------|----------------|--------------|------------|------------|------------|------|----------------|--------------|---------------------------------------|--|
| mm | 5.2 5.0 | 0.48 0.40 | 0.66 0.55 | 0.45 0.38 | 4.8 4.4 | 1.7 1.4 | 4.2 3.6 | 2.54 | 1.27 | 14.5 12.7 | 2.5 | |

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

| OUTLINE | REFERENCES | | | | | | | |
|---------|------------|-------|--------|--|--|---------------------------------|--|--|
| VERSION | IEC | JEDEC | JEITA | | | ISSUE DATE | | |
| SOT54 | | TO-92 | SC-43A | | | 97-02-28 04-06-28 | | |

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PNP high voltage transistors

BF421; BF423

DATA SHEET STATUS

| LEVEL | DATA SHEET STATUS ⁽¹⁾ | PRODUCT STATUS(2)(3) | DEFINITION |
|-------|-------------------------------------|-------------------------|--|
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- 3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

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